

| APTM120DA30T1G | |
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| Teilenummer | APTM120DA30T1G |
| Hersteller | Microsemi |
| Beschreibung | MOSFET N-CH 1200V 31A SP1 |
| Verfügbare Menge | 500 pcs in stock |
| Datenblätter | APTM120DA30T1G.pdf |
| APTM120DA30T1G Price | Preis und Lieferzeit online anfordern or Email us: Info@ariat-tech.com |


[EIN ANGEBOT BEKOMMEN](#)

| Technische Information von APTM120DA30T1G | | | |
|---|--------------------------------|---|-----------------------------|
| Hersteller-Teilenummer | APTM120DA30T1G | Kategorie | Diskrete Halbleiterprodukte |
| Hersteller | Microsemi | Beschreibung | MOSFET N-CH 1200V 31A SP1 |
| Paket / Fall | Bulk | Verfügbare Menge | 500 |
| VGS (th) (Max) @ Id | 5V @ 2.5mA | Technologie | MOSFET (Metal Oxide) |
| Supplier Device-Gehäuse | SP1 | Serie | - |
| Rds On (Max) @ Id, Vgs | 360 mOhm @ 25A, 10V | Verlustleistung (max) | 657W (Tc) |
| Verpackung | Bulk | Verpackung / Gehäuse | SP1 |
| Betriebstemperatur | -40°C ~ 150°C (TJ) | Befestigungsart | Chassis Mount |
| Eingabekapazität (Ciss) (Max) @ Vds | 14560pF @ 25V | Gate Charge (Qg) (Max) @ Vgs | 560nC @ 10V |
| Typ FET | N-Channel | FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 1200V (1.2kV) | Strom - Ununterbrochener Abfluss (Id) bei 25 °C | 31A |

APTM120DA30T1G 500 pcs Neu und original auf Lager, APTM120DA30T1G-Bestand finden, Datenblatt, PDF, Inventar bei Ariat-Tech.com online, APTM120DA30T1G Microsemi mit Garantie und Vertrauen bestellen. Anfrage APTM120DA30T1G: Info@Ariat-Tech.com

Zugehörige Teile für APTM120DA30T1G

| Bild | Teilenummer | Beschreibung | Hersteller | Menge |
|------|---------------------------------|----------------------------|-----------------------|---------|
| | APTM120A80FT1G | MOSFET 2N-CH 1200V 14A SP1 | Microsemi Corporation | 500 pcs |
| | APTM10UM02FAG | MOSFET N-CH 100V 570A SP6 | Microsemi Corporation | 500 pcs |
| | APTM120H140FT1G | MOSFET 4N-CH 1200V 8A SP1 | Microsemi Corporation | 500 pcs |
| | APTM120DA68T1G | MOSFET N-CH 1200V 15A SP1 | Microsemi Corporation | 500 pcs |
| | APTM120H57FT3G | MOSFET 4N-CH 1200V 17A SP3 | Microsemi Corporation | 500 pcs |
| | APTM120A20SG | MOSFET 2N-CH 1200V 50A SP6 | Microsemi Corporation | 500 pcs |
| | APTM120H57FTG | MOSFET 4N-CH 1200V 17A SP4 | Microsemi Corporation | 500 pcs |
| | APTM120A15FG | MOSFET 2N-CH 1200V 60A SP6 | Microsemi Corporation | 500 pcs |
| | APTM120DU29TG | MOSFET 2N-CH 1200V 34A SP4 | Microsemi Corporation | 500 pcs |
| | APTM120DU15G | MOSFET 2N-CH 1200V 60A SP6 | Microsemi Corporation | 500 pcs |
| | APTM120A65FT1G | MOSFET 2N-CH 1200V 16A SP1 | Microsemi Corporation | 500 pcs |
| | APTM120A20DG | MOSFET 2N-CH 1200V 50A SP6 | Microsemi Corporation | 500 pcs |
| | APTM120DA15G | MOSFET N-CH 1200V 60A SP6 | Microsemi Corporation | 500 pcs |
| | APTM120DDA57T3G | MOSFET 2N-CH 1200V 17A SP3 | Microsemi Corporation | 500 pcs |
| | APTM120DA56T1G | MOSFET N-CH 1200V 18A SP1 | Microsemi Corporation | 500 pcs |
| | APTM120H29FG | MOSFET 4N-CH 1200V 34A SP6 | Microsemi Corporation | 500 pcs |
| | APTM120A29FTG | MOSFET 2N-CH 1200V 34A SP4 | Microsemi Corporation | 500 pcs |
| | APTM120DA29TG | MOSFET N-CH 1200V 34A SP4 | Microsemi Corporation | 500 pcs |
| | APTM120DSK57T3G | MOSFET 2N-CH 1200V 17A SP3 | Microsemi Corporation | 500 pcs |
| | APTM120DA30CT1G | MOSFET N-CH 1200V 31A SP1 | Microsemi Corporation | 500 pcs |

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|---|---|---|---|
| APTM120DA30T1G-Lager | APTM120DA30T1G Preis | APTM120DA30T1G-Elektronik | APTM120DA30T1G-Komponenten |
| APTM120DA30T1G Inventar | APTM120DA30T1G Digikey | Lieferant APTM120DA30T1G | APTM120DA30T1G online bestellen |
| Anfrage APTM120DA30T1G | APTM120DA30T1G-Bild | APTM120DA30T1G Bild | APTM120DA30T1G PDF |
| APTM120DA30T1G Datenblatt | APTM120DA30T1G Datenblatt herunterladen | Hersteller Microsemi | |

Händler für Elektronikkomponenten - IC-Chips & IGBT-Modullieferant.

Angebotsanfrage E-Mail: Info@ariat-tech.com Webseite: [https:// www. ariat-tech .com](https://www.ariat-tech.com)

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